

Supporting information for

Multi-functional molecule advancing the efficiency of pure 3D FASnI₃ perovskite solar cells based on tin tetraiodide reduction method

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Materials and Methods

Materials

Anhydrous solvents including N, N-dimethylformamide (DMF), dimethyl sulfoxide (DMSO), chlorobenzene (CB), isopropanol (IPA), were purchased from Sigma-Aldrich. Formamidinium iodide (FAI, 99.99%) was purchased from Great Cell Solar. Tin iodide (SnI₂, AnhydroBeads, 99.99%) was obtained from Sigma-Aldrich. Tin iodide (SnI₄, Anhydrous, 99.998%) and Phenylhydrazine-4-sulfonic acid (PHPA) were obtained from Macklin. Formamidinium Iodide (FAI) was purchased from Great Cell Solar (Australia). Bathocuproine (BCP), PCBM and ICBA were obtained from 1-Materials. UV curing sealant was purchased from Blufixx for the encapsulation process. Aluminum (Al) were obtained from commercial sources with high purity ($\geq 99.9\%$).

Preparation of perovskite precursor solutions

For pristine FASnI₃, 137.6 mg FAI, 298.1 mg SnI₂, 13.5 mg SnF₂ and 100mg Sn powder were dissolved in 1 ml DMF and DMSO solution (volume ratio 3:1) and stirred at room temperature for 12 hours. For TTR FASnI₃, 137.6 mg FAI, 250.5 mg SnI₄, 13.5 mg SnF₂ and 100mg Sn powder were dissolved in 1 ml DMF and DMSO solution (volume ratio 3:1) and stirred at room temperature for 12 hours. For the PHPA solution, another 0.5-3 mg/ml PHPA was added in the preceding solution of TTR FASnI₃.

Device Fabrication

The patterned ITO glass substrates were cleaned using detergent, deionized water, acetone, and isopropanol in an ultrasonic bath for 20 minutes, sequentially. Then, the substrates were dried with N₂ flow and cleaned with UV-Ozone for 30 mins. After that, the PEDOT: PSS layers were deposited on the ITO glass substrates by spin-coating at 5000 rpm for 40 s, followed by post annealing at 140 °C for 10 min. The deposition of the Sn-perovskite films was performed in an N₂ glove box with the oxygen < 0.1 ppm. All the precursor solutions were filtered with a 0.45 μm PTFE filter and

dropped onto PEDOT: PSS/ITO substrates, subsequently spin-coating at the speed of 5000 rpm for 60 s. All the perovskite films were treated by drop-casting 300 μ L chlorobenzene as the anti-solvent during the spinning process at about 40 seconds. Then, all the films were post-annealed at 80 $^{\circ}$ C for 15 min. Then, 40 μ L of ICBA or PCBM (20 mg/mL in CB) solution was spin-coated on the top of perovskite film at the speed of 1200 rpm for the 30s and annealed at 80 $^{\circ}$ C for 10 min. Finally, 5 nm BCP and 70 nm Al were evaporated on top of the film through a shadow mask by thermal evaporation. UV curable sealants with glass slides were applied to encapsulate the devices.

Film Characterizations

X-ray diffraction (XRD) spectra were collected using the Rigaku MiniFlex600 X-ray diffractometer (Cu $K\alpha$, 1.5406 \AA). Top-view and cross-section morphology of the perovskite films were measured by a high-resolution field emission scanning electron microscope (SEM, TESCAM MIRA3). The absorption spectra were taken using a Shimadzu ultraviolet-visible spectrophotometer (UV-3600). Room-temperature photoluminescence (PL) spectra were measured by Spectrofluorometer (FS5, Edinburgh instruments) with 405 nm pulsed laser. X-ray photoelectron spectroscopy (XPS) measurements were carried out on an Omicron ESCA Probe XPS spectrometer (Thermo Scientific ESCALAB 250Xi). The XPS spectra were calibrated by the binding energy of 284.8 eV for C 1s. Fourier-transform infrared spectroscopy (FTIR) was measured by Fourier Transform Infrared Spectrometer (Bruker Vertex 70v) for 4000 to 400 cm^{-1} . Contact angle measurements were carried out with a KLA-Tencore D120 surface profiler. NMR spectra were recorded on Bruker Avance 500 and Bruker Avance 400 spectrometers in DMSO-d_6 . The pH of the precursor solution was measured using a Rex Electric Chemical E-301-QC pH meter, which was calibrated with three standard solutions before each test.

Device Characterization

J-V measurements were carried out using a Keithley 2400 source meter in an ambient environment (roughly 20 $^{\circ}$ C and 60% relative humidity). The encapsulated devices were measured both in reverse scan (0.9 to -0.2 V, steps of 0.01 V) and forward scan (-0.2 to 0.9 V, steps of 0.01 V) with 200 ms delay time. Illumination was provided by an Oriel Sol3A solar simulator with an AM 1.5G spectrum, and light intensity of 100 mW cm^{-2} was calibrated by a standard KG-5 Si diode. The active area (0.08 cm^2) of our device was calibrated with a shadow mask during measurements. Electrochemical impedance spectroscopy and Mott-Schottky plots were conducted on the Zahner Zennium electrochemical workstation. EQE measurements for devices were carried out with an Enli-Tech EQE measurement system, and light intensity at each wavelength was calibrated with a standard single-crystal Si photovoltaic cell. Long-term operational stability was conducted with the encapsulated devices under a 1-sun-equivalent light-emitting diode lamp under an ambient environment (approximately 25 $^{\circ}$ C and 50% relative humidity). The maximum power point was recorded every 60 s. TPV and TPC measurement were carried out by 405 nm pulsed laser and oscilloscope (TDS 2024C), with frequencies set to 10Hz (TPV) and 1000Hz (TPA).

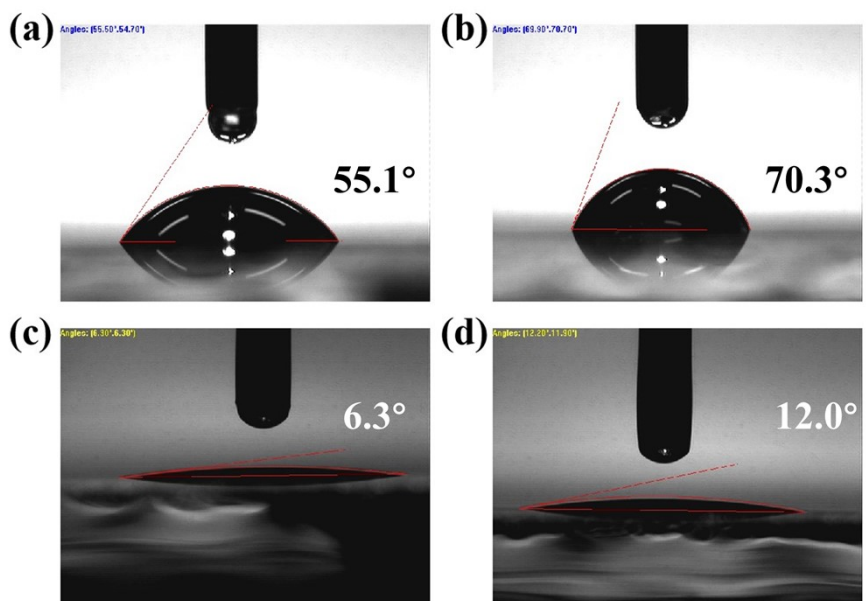


Figure S1. Perovskite film contact angle test results: (a)pristine, water. (b)TTR, water. (c)pristine, n-hexadecane. (d)TTR, n-hexadecane.

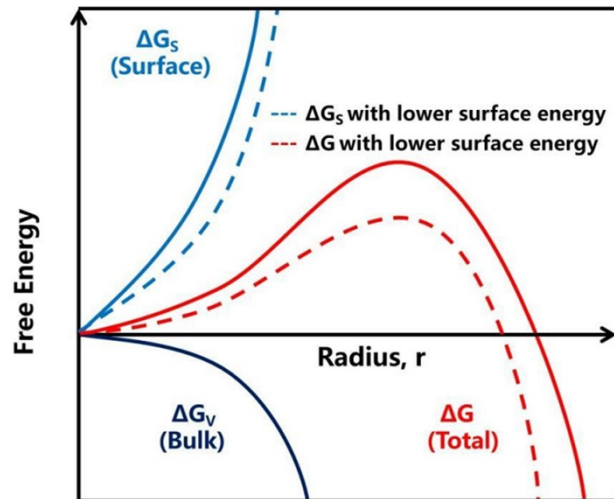


Figure S2. Schematic diagram of the classical free energy diagram for nucleation as a function of particle radius. ¹

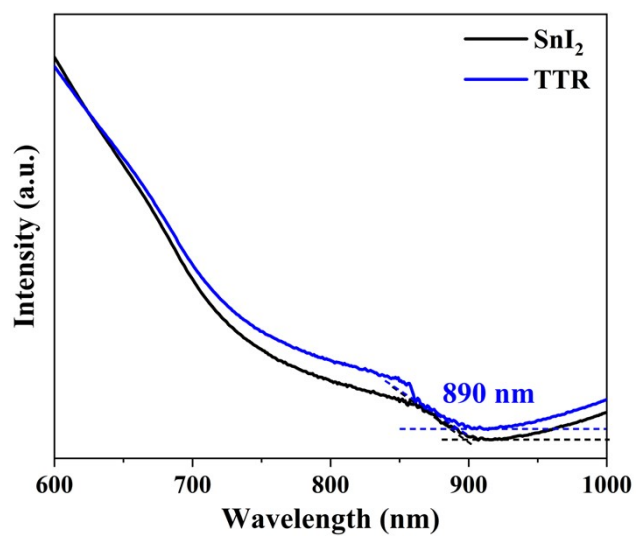


Figure S3. UV-vis absorption of pristine and TTR perovskite films.

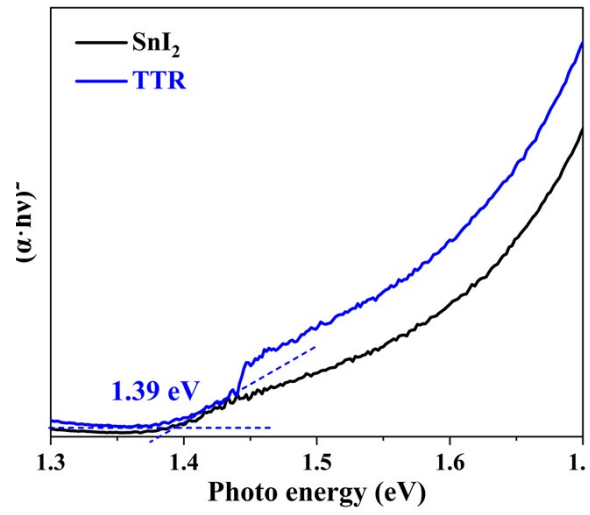


Figure S4. Tauc plot of the pristine and TTR perovskite films.

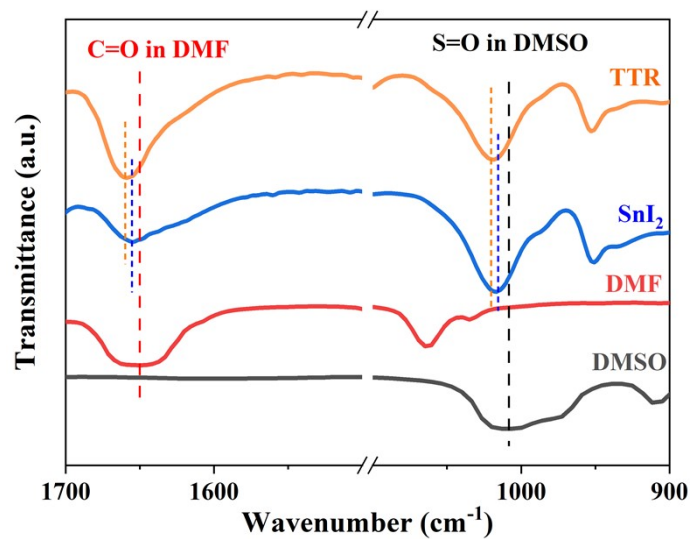


Figure S5. FTIR spectra of SnI₂ and TTR with DMSO/DMF.

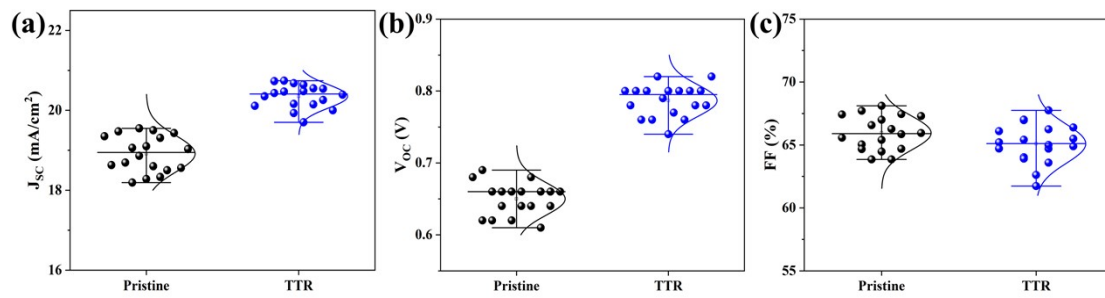
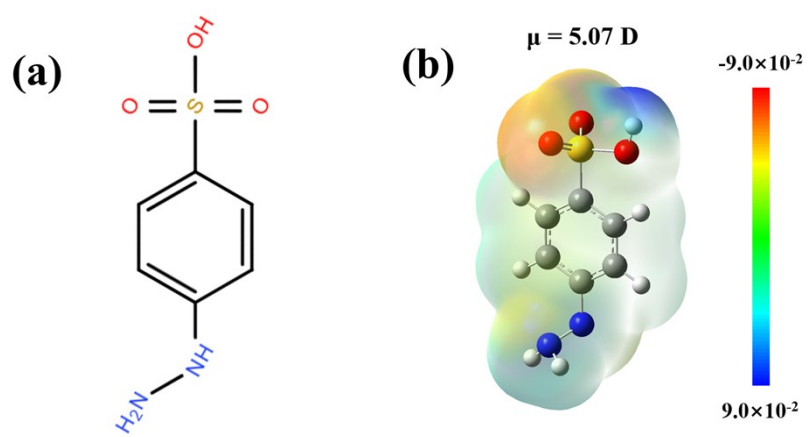


Figure S6. Box plot chart of a) J_{sc} , b) V_{oc} and c) FF of the pristine devices and TTR devices.



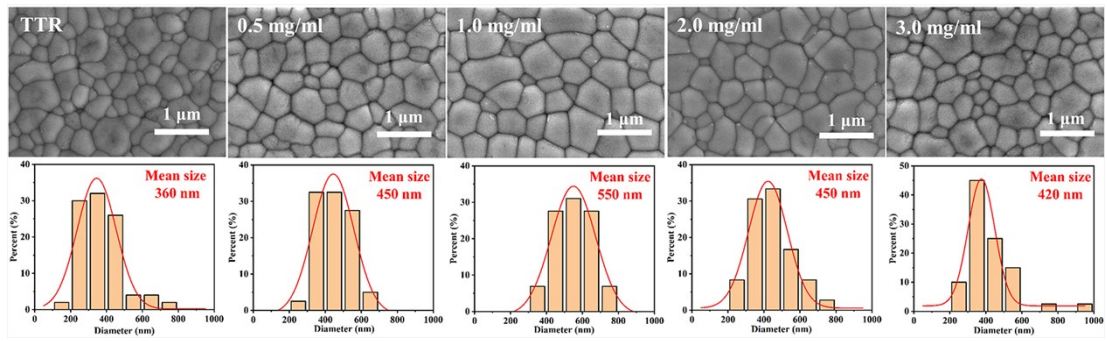


Figure S8. The SEM images and particle size distribution of TTR film with different addition concentrations of PHPA.

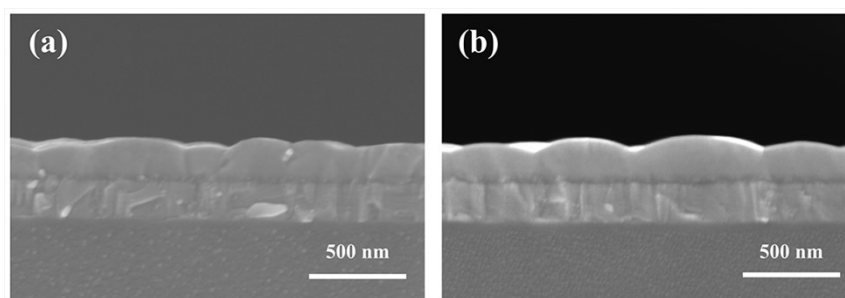


Figure S9. The cross-sectional SEM images of TTR film a) without and b) with PHPA.

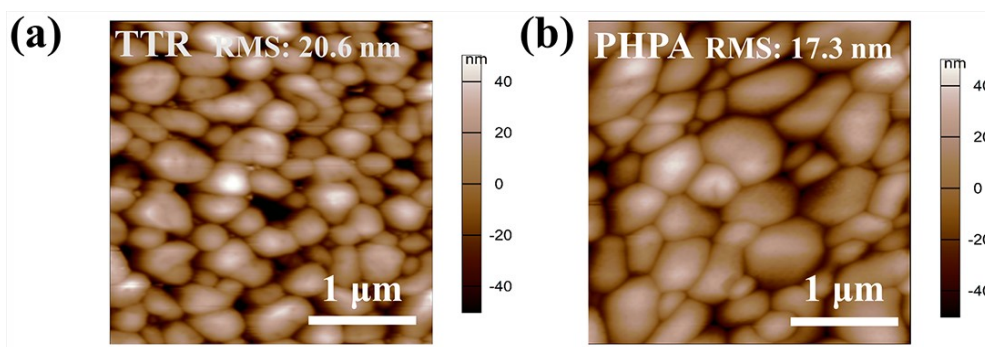


Figure S10. AFM measurements of TTR film a) without and b) with PHPA.

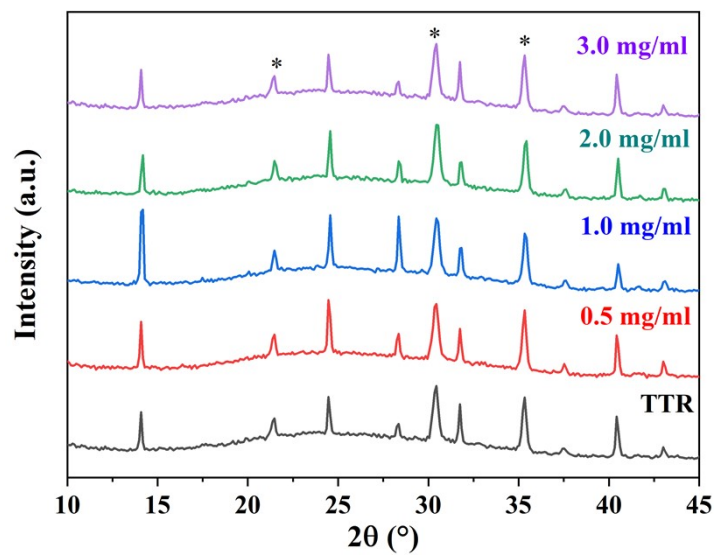


Figure S11. XRD patterns of TTR perovskite film with different addition concentrations of PHPA.

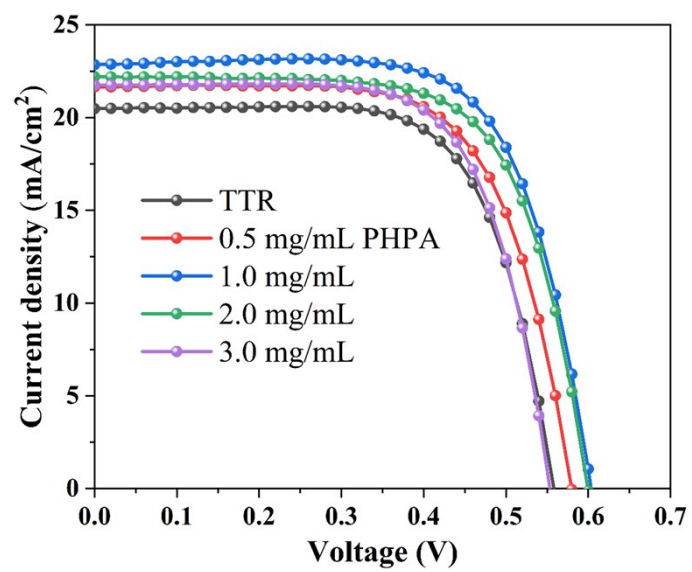


Figure S12. J-V curves of PSCs with different addition concentrations of PHPA using PCBM.

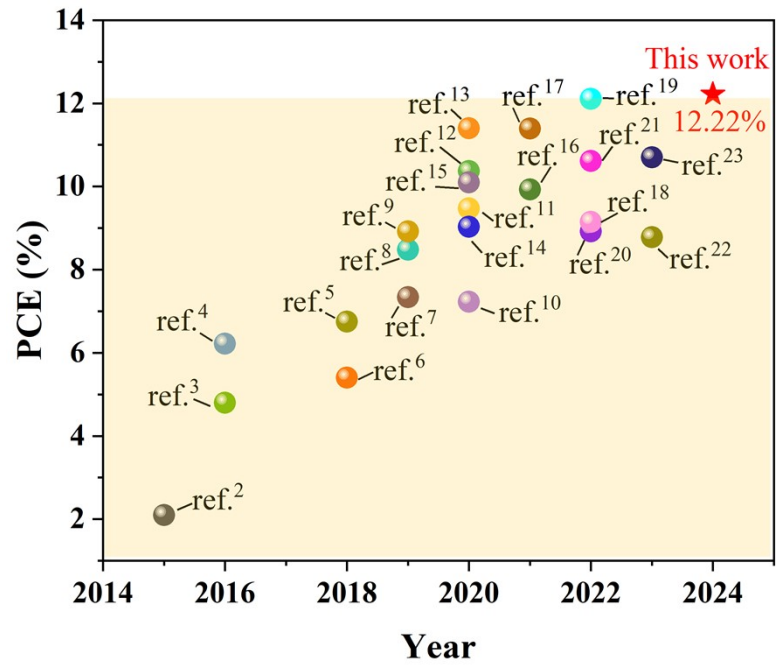


Figure S13. The efficiency development diagram of pure 3D FASnI₃ perovskite solar cells. ²⁻²³

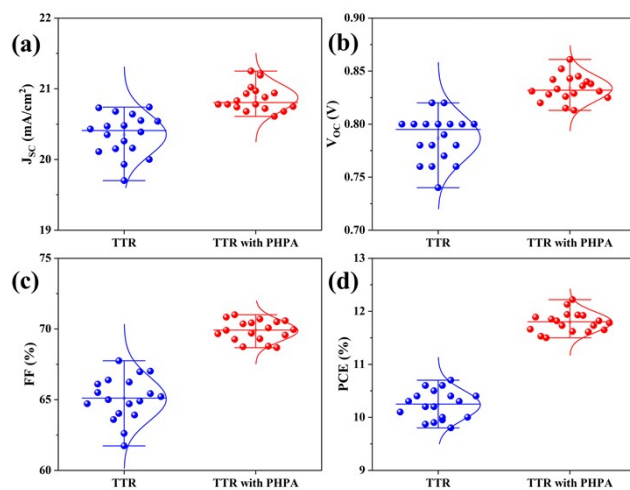


Figure S14. Statistic photovoltaic parameters of independent PSCs based on FASnI₃ films by the TTR and TTR with PHPA.

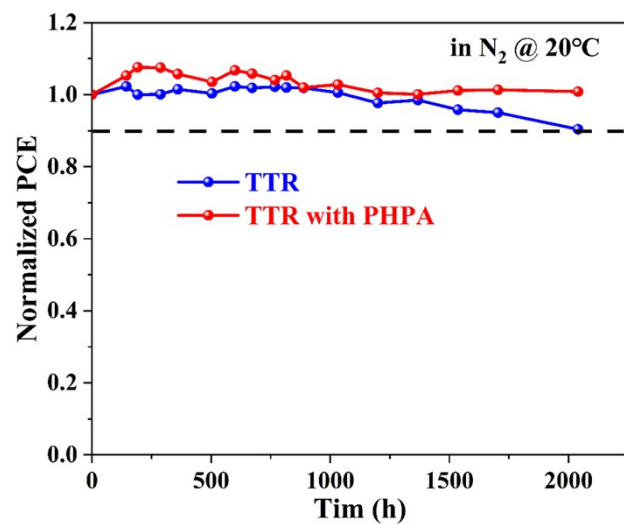


Figure S15. The long-term stability in N_2 under dark conditions for the TTR and PHPA devices

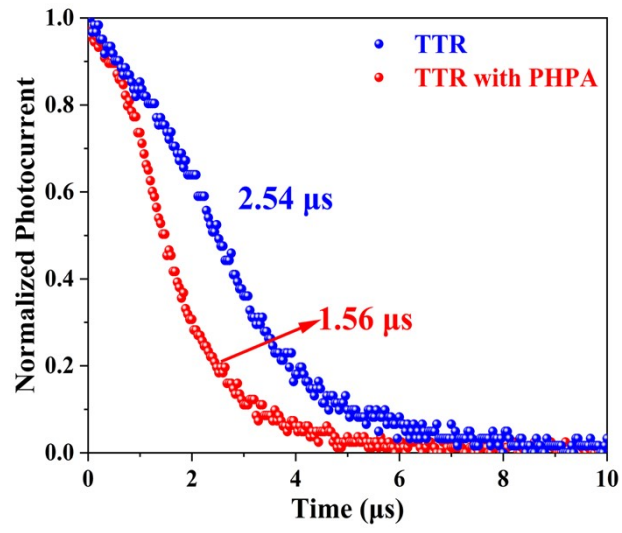


Figure S16. The TPC measurements of the TTR and PHPA perovskite devices.

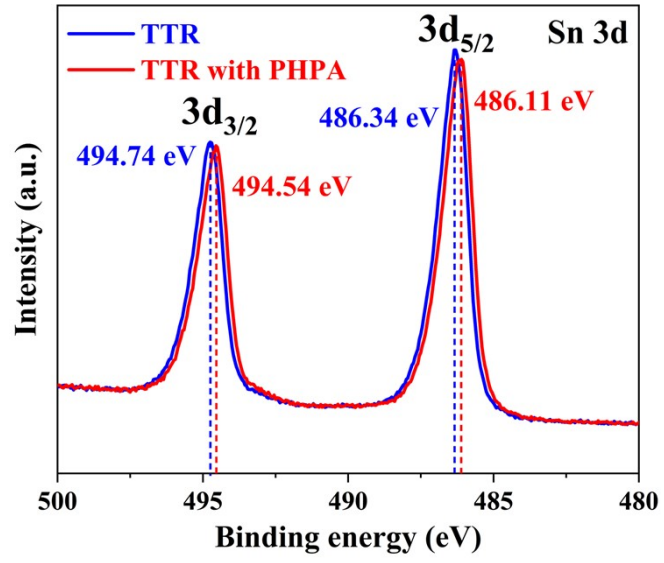


Figure S17. The XPS peaks of Sn 3d for the TTR and PHPA perovskite films.

Table S1. Contact angle (CA) and surface energy of different perovskite films.

| Sn ²⁺ source | Hexadecane CA (°) | Water CA (°) | Surface energy (mJ·m ⁻²) | | |
|-------------------------|-------------------|--------------|--------------------------------------|-----------------|-------|
| | | | Dispersive Component | Polar Component | Total |
| SnI ₂ | 6.3 | 55.1 | 27.43 | 21.06 | 48.49 |
| TTR | 12.0 | 70.3 | 27.00 | 11.68 | 38.68 |

Table S2. Standard potential of Tin element (Handbook of Chemistry and Physics, 2017).

| Reaction | Potential (V) |
|--|---------------|
| Sn ²⁺ + 2 e ⁻ → Sn (0) | -0.1375 |
| Sn ⁴⁺ + 2 e ⁻ → Sn ²⁺ | +0.1510 |
| Sn ⁴⁺ + 4 e ⁻ → Sn (0) | +0.0135 |

Table S3. The Fitting results of the TRPL spectra of TTR and PHPA perovskite films.

| | A ₁ | τ ₁ (ns) | A ₂ | τ ₂ (ns) | R ² | τ _{ave} (ns) |
|------|----------------|---------------------|----------------|---------------------|----------------|-----------------------|
| TTR | 0.9205 | 0.9278 | 0.1674 | 3.9941 | 0.9974 | 2.2742 |
| PHPA | 0.5166 | 1.7038 | 0.4842 | 5.5678 | 0.9996 | 4.6168 |

Table S4. The fitting results of XPS spectra for TTR and PHPA perovskite films.

| | | Sn 3d _{5/2} | | Sn 3d _{3/2} | | Sn ²⁺ (%) | Sn ⁴⁺ (%) |
|------|---------------|----------------------|------------------|----------------------|------------------|----------------------|----------------------|
| | | Sn ²⁺ | Sn ⁴⁺ | Sn ²⁺ | Sn ⁴⁺ | | |
| TTR | Position (eV) | 486.0 | 486.7 | 494.4 | 495.2 | 75.83 | 24.17 |
| | peak area | 300895 | 95865 | 208354 | 66393 | | |
| PHPA | Position (eV) | 486.1 | 486.8 | 494.5 | 495.3 | 88.40 | 11.60 |
| | peak area | 312650 | 41105 | 216530 | 28345 | | |

Table S5. The detail data of the J-V curves of PSCs with PHPA using PCBM.

| | J _{SC} (mA/cm ²) | V _{OC} (V) | FF (%) | PCE (%) |
|-----------|---------------------------------------|---------------------|--------|---------|
| TTR | 20.48 | 0.56 | 68.58 | 7.86 |
| 0.5 mg/ml | 22.27 | 0.58 | 67.34 | 8.70 |
| 1.0 mg/ml | 22.85 | 0.60 | 69.91 | 9.58 |
| 2.0 mg/ml | 22.21 | 0.60 | 68.30 | 9.10 |
| 3.0 mg/ml | 21.76 | 0.56 | 67.85 | 8.27 |

Table S6. Fitting parameters of PSCs from Nyquist plots.

| | R _s (Ω) | R _{rec} (Ω) |
|------|--------------------|----------------------|
| TTR | 14.4 | 1020 |
| PHPA | 15.1 | 3500 |

Reference

1. J.-W. Lee, D.-K. Lee, D.-N. Jeong and N.-G. Park, *Adv. Funct. Mater.*, 2019, **29**, 1807047.
2. T. M. Koh, T. Krishnamoorthy, N. Yantara, C. Shi, W. L. Leong, P. P. Boix, A. C. Grimsdale, S. G. Mhaisalkar and N. Mathews, *J. Mater. Chem. A*, 2015, **3**, 14996-15000.
3. S. J. Lee, S. S. Shin, Y. C. Kim, D. Kim, A. Tae Kyu, J. H. Noh, J. Seo and S. I. Seok, *J. Am. Chem. Soc.*, 2016, **138**, 3974-3977.
4. W. Liao, D. Zhao, Y. Yu, C. R. Grice, C. Wang, A. J. Cimaroli, P. Schulz, W. Meng, K. Zhu, R.-G. Xiong and Y. Yan, *Adv. Mater.*, 2016, **28**, 9333-9340.
5. F. Gu, S. Ye, Z. Zhao, H. Rao, Z. Liu, Z. Bian and C. Huang, *Sol. RRL*, 2018, **2**, 1800136.
6. M. E. Kayesh, T. H. Chowdhury, K. Matsuishi, R. Kaneko, S. Kazaoui, J.-J. Lee, T. Noda and A. Islam, *ACS Energy Lett.*, 2018, **3**, 1584-1589.
7. J. Cao, Q. Tai, P. You, G. Tang, T. Wang, N. Wang and F. Yan, *J. Mater. Chem. A*, 2019, **7**, 26580-26585.
8. F. Li, H. Fan, J. Zhang, J.-H. Huang, P. Wang, C. Gao, L.-M. Yang, Z. Zhu, A. K.-Y. Jen, Y. Song and K.-J. Jiang, *Sol. RRL*, 2019, **3**, 1900285.
9. X. Meng, J. Lin, X. Liu, X. He, Y. Wang, T. Noda, T. Wu, X. Yang and L. Han, *Adv. Mater.*, 2019, **31**, 1903721.
10. W. Gu, X. Xu, J. Chen, B. Ma, M. Qin, W. Zhu, J. Qian, Z. Qin, W. Shen, Y. Lu, W. Zhang, S. Chen, X. Lu and W. Huang, *Sol. RRL*, 2020, **4**, 2000153.
11. X. He, T. Wu, X. Liu, Y. Wang, X. Meng, J. Wu, T. Noda, X. Yang, Y. Moritomo, H. Segawa and L. Han, *J. Mater. Chem. A*, 2020, **8**, 2760-2768.
12. X. Meng, T. Wu, X. Liu, X. He, T. Noda, Y. Wang, H. Segawa and L. Han, *J. Phys. Chem. Lett.*, 2020, **11**, 2965-2971.
13. C. Wang, F. Gu, Z. Zhao, H. Rao, Y. Qiu, Z. Cai, G. Zhan, X. Li, B. Sun, X. Yu, B. Zhao, Z. Liu, Z. Bian and C. Huang, *Adv. Mater.*, 2020, **32**, 1907623.
14. T. Wang, Q. Tai, X. Guo, J. Cao, C.-K. Liu, N. Wang, D. Shen, Y. Zhu, C.-S. Lee and F. Yan, *ACS Energy Lett.*, 2020, **5**, 1741-1749.
15. T. Wu, X. Liu, X. He, Y. Wang, X. Meng, T. Noda, X. Yang and L. Han, *Sci. China Chem.*, 2020, **63**, 107-115.
16. Z. Dai, T. Lv, J. Barbaud, W. Tang, T. Wang, L. Qiao, H. Chen, R. Zheng, X. Yang and L. Han, *Sci. China Mater.*, 2021, **64**, 2645-2654.
17. X. Meng, Y. Li, Y. Qu, H. Chen, N. Jiang, M. Li, D.-J. Xue, J.-S. Hu, H. Huang and S. Yang, *Angew. Chem. Int. Ed.*, 2021, **60**, 3693-3698.
18. B. H. Chang, B. Li, Z. X. Wang, H. Li, L. Wang, L. Pan, Z. H. Li and L. W. Yin, *Adv. Funct. Mater.*, 2022, **32**, 2107710.
19. H. Jang, H. Y. Lim, Y. J. Yoon, J. Seo, C. B. Park, J. G. Son, J. W. Kim, Y. S. Shin, N. G. An, S. J. Choi, S. H. Kim, J. Jeong, Y. Jo, S. K. Kwak, D. S. Kim and J. Y. Kim, *Sol. RRL*, 2022, **6**, 2200789.
20. M. A. Karim, K. Matsuishi, T. H. Chowdhury, M. Abdel-Shakour, Y. He and A. Islam, *ACS Appl. Energy Mater.*, 2022, **5**, 15038-15047.
21. J. Sanchez-Diaz, R. S. Sánchez, S. Masi, M. Krečmarová, A. O. Alvarez, E. M. Barea, J. Rodriguez-Romero, V. S. Chirvony, J. F. Sánchez-Royo, J. P. Martinez-Pastor and I. Mora-Seró, *Joule*, 2022, **6**, 861-883.

22. J. Choi, S. J. Yang, S. G. Han, W. Sung, D. Yoo and K. Cho, *Chem. Mater.*, 2023, **35**, 1148-1158.
23. G. Zeng, D. Pu, L. Huang, H. Guan, S. Zhou, J. Zhou, W. Shen, G. Li, G. Fang and W. Ke, *J. Mater. Chem. A*, 2023, **11**, 11245-11253.